

MiniSKiiP® 0

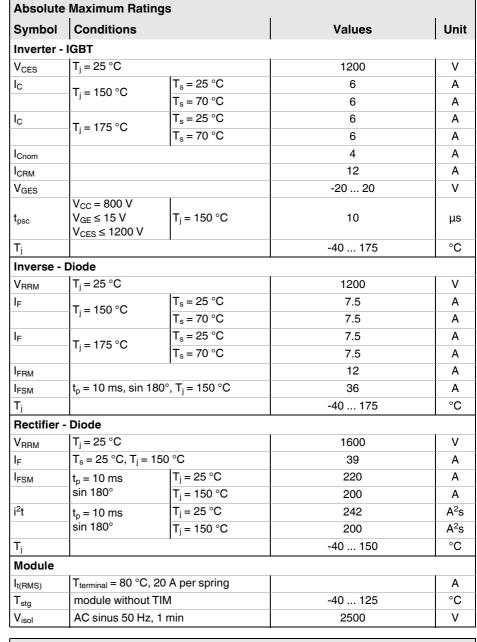
SKiiP 02NAC12T4V1

Features*

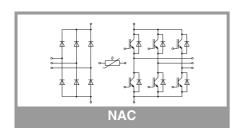
- Trench 4 IGBTs
- · Robust and soft switching freewheeling diodes in CAL technology
- · Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

Remarks

- · Max. case temperature limited to T_C=T_S=125 °C
- · Product reliability results valid for T_i≤150 °C (recommended T_{j,op}=-40...+150 °C)
- MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information.
- · For storage and case temperature with TIM see document: "Technical **Explanations Thermal Interface** Materials"



Characteristics								
Symbol	Conditions	min.	typ.	max.	Unit			
Inverter -	IGBT		•			•		
V _{CE(sat)}	$I_C = 4 A$	T _j = 25 °C		1.85	2.10	V		
	V _{GE} = 15 V chiplevel	T _j = 150 °C		2.25	2.45	V		
V_{CE0}	chiplevel	T _j = 25 °C		0.80	0.90	V		
	Criipievei	T _j = 150 °C		0.70	0.80	V		
r _{CE}	V _{GE} = 15 V	T _j = 25 °C		263	300	mΩ		
	chiplevel	T _j = 150 °C		388	413	mΩ		
$V_{\text{GE(th)}}$	$V_{GE} = V_{CE} V$, $I_C = 1 \text{ mA}$		5	5.8	6.5	V		
I _{CES}	$V_{GE} = 0 V$	T _j = 25 °C			1	mA		
	V _{CE} = 1200 V			-		mA		
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		0.25		nF		
Coes		f = 1 MHz		0.03		nF		
C _{res}		f = 1 MHz		0.02		nF		





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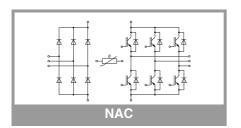
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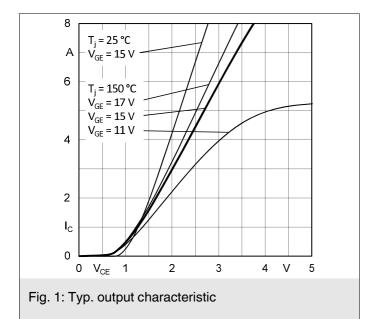
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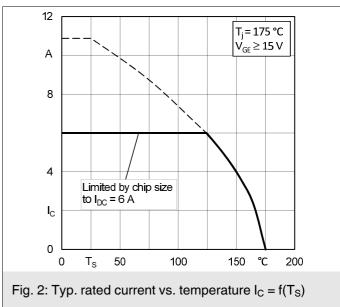
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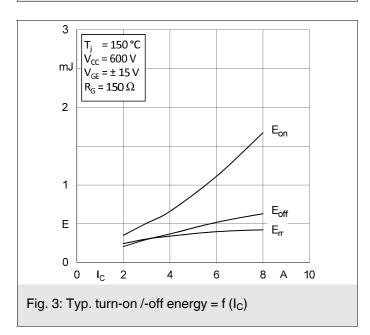
Characteristics								
Symbol	Conditions		min.	typ.	max.	Unit		
Inverter - IGBT								
Q _G	V _{GE} = - 8 V+ 15 V			nC				
R _{Gint}	T _j = 25 °C			0		Ω		
t _{d(on)}	V _{CC} = 600 V	T _j = 150 °C		65		ns		
t _r	I _C = 4 A	T _j = 150 °C	45			ns		
Eon	$R_{G \text{ on}} = 150 \Omega$ $R_{G \text{ off}} = 150 \Omega$	T _j = 150 °C	0.66			mJ		
t _{d(off)}	11G off = 130 32	T _j = 150 °C	300			ns		
t _f		T _j = 150 °C		110		ns		
E _{off}	$V_{GE} = +15/-15 \text{ V}$	T _j = 150 °C		0.37		mJ		
R _{th(j-s)}	per IGBT, λ _{paste} =0	.8 W/(K*m)		K/W				
Inverse -	Diode							
$V_F = V_{EC}$	I _F = 4 A	T _j = 25 °C		1.82	2.08	V		
	V _{GE} = 0 V chiplevel	T _j = 150 °C		1.63	1.89	V		
V _{F0}	chinlevel	T _j = 25 °C		1.30	1.50	V		
	chiplevel	T _j = 150 °C		0.90	1.10	V		
r _F	chiplevel	$T_j = 25 ^{\circ}C$		129	144	mΩ		
		T _j = 150 °C		181	198	mΩ		
I _{RRM}	I _F = 4 A	T _j = 150 °C		3.4		Α		
Q _{rr}	V _{GE} = -15 V V _{CC} = 600 V	T _j = 150 °C		0.95		μC		
E _{rr}	$di/dt_{off} = 110 \text{ A/}\mu\text{s}$	T _j = 150 °C		0.34		mJ		
R _{th(j-s)}	per Diode, λ _{paste} =0	0.8 W/(K*m)		K/W				
Rectifier -	- Diode							
$V_F = V_{EC}$	I _F = 8 A	T _j = 25 °C		1.00	1.21	V		
	I _F = 8 A chiplevel	T _j = 125 °C		0.90	1.10	V		
V_{F0}	obiployol	T _j = 25 °C		0.88	0.98	V		
	chiplevel	T _j = 125 °C		0.73	0.83	V		
r _F	chiplevel	T _j = 25 °C		15	29	mΩ		
	Chipievei	T _j = 125 °C		21	34	mΩ		
R _{th(j-s)}	per Diode, λ _{paste} =0).8 W/(K*m)		1.5		K/W		
Module								
Ms	to heat sink		2		2.5	Nm		
w				20		g		
Temperat	ture Sensor			<u>-</u>				
R ₁₀₀	T _r = 100 °C, tolera	T _r = 100 °C, tolerance = 3 %		1670 ± 3%		Ω		
R _(T)	$R_{(T)}$ =1000Ω[1+A(⁻], A = 7.635*10 ⁻³ °C B = 1.731*10 ⁻⁵ °C		·					

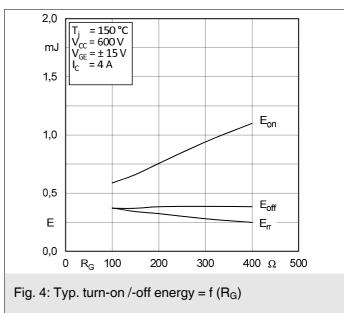
Creepage distance (spring to spring) between temperature sensor and DC- = $3.3 \, \text{mm}$ (CTI 600)

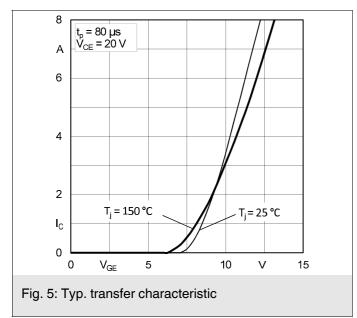


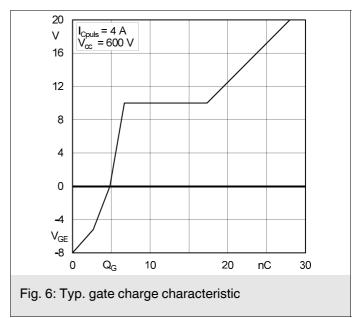


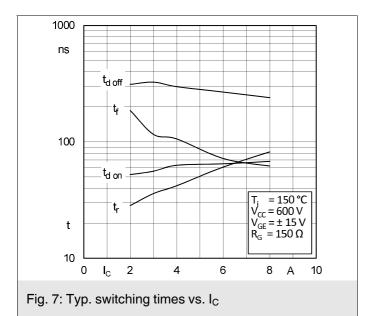


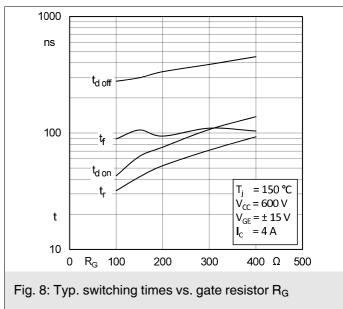


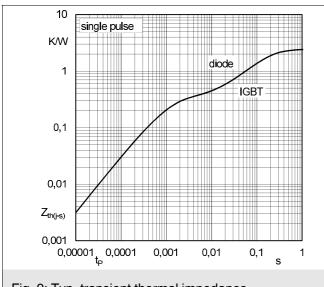




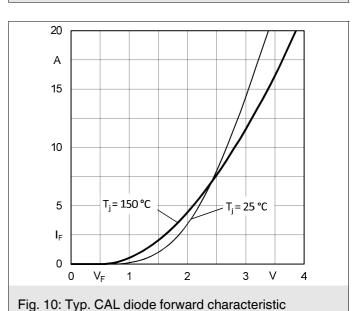


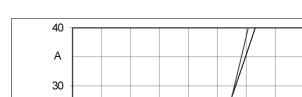












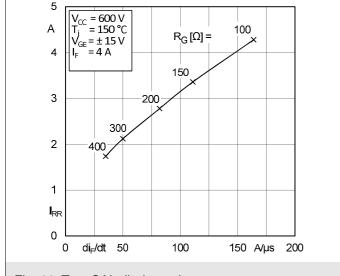


Fig. 11: Typ. CAL diode peak reverse recovery current

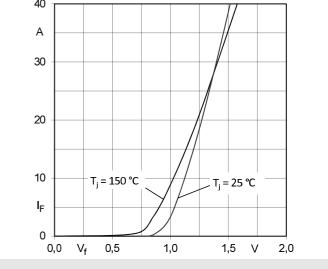
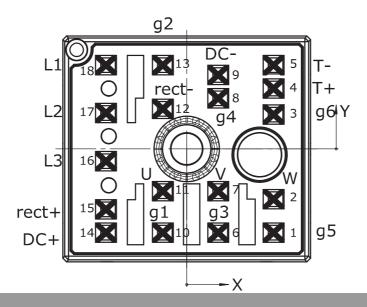


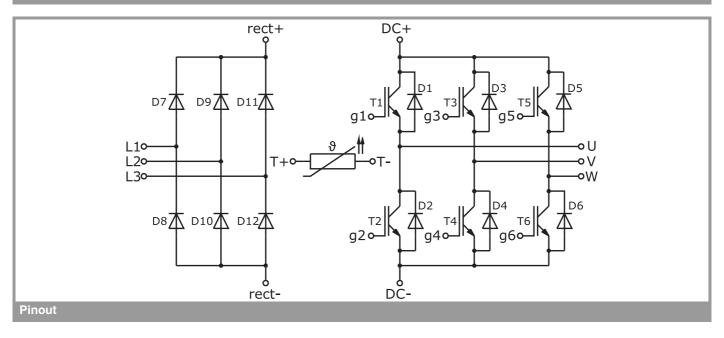
Fig. 12: Typ. input bridge forward characteristic

Pin out							
Pin	X	Y	Function	Pin	X	Υ	Function
1	11,93	-11,50	g5	10	-3,28	-11,50	g1
2	11,93	-6,90	W	11	-3,28	-5,80	U
3	11,93	4,71	g6	12	-3,28	5,50	rect-
4	11,93	8,3	T+	13	-3,28	11,50	g2
5	11,93	11,50	T-	14	-11,08	-11,50	DC+
6	4,33	-11,50	g3	15	-11,08	-8,30	rect+
7	4,33	-5,80	V	16	-11,08	-1,68	L3
8	4,33	6,95	g4	17	-11,08	4,93	L2
9	4,33	10,15	DC-	18	-11,08	11,50	L1

all values in mm



Pinout and Dimensions



This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

*IMPORTANT INFORMATION AND WARNINGS

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